November 2007



SEMICONDUCTOR®

# FFPF20UP60DN

# Features

- High Speed Switching,  $t_{rr}$  < 70ns @  $I_F$  = 10A
- High Reverse Voltage and High Reliability
- RoHS compliant

# Applications

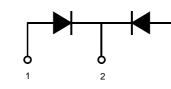
- General Purpose
- Switching Mode Power Supply
- Boost Diode in continuous mode power factor corrections
- Power switching circuits



# 20A, 600V Ultrafast Rectifier

The FFPF20UP60DN is a ultrafast rectifier with soft recovery characteristics. It is silicon nitride passivated ion-implanted epitaxial planar construction.

This device is intended for use as freewheeling of boost diode in switching power supplies and other power swithching applications. It's low stored charge and ultrarfast soft recovery with soft recovery characteristics minimize ringing and electrical noise in many power switching, thus reducing power loss in the switching transistors.



1. Anode 2. Cathode 3. Anode

3

### Absolute Maximum Ratings T<sub>C</sub> = 25°C unless otherwise noted

TO-220F

Symbol	Parameter	Ratings	Units	
V <sub>RRM</sub>	Peak Repetitive Reverse Voltage	600	V	
V <sub>RWM</sub>	Working Peak Reverse Voltage	600	V	
V <sub>R</sub>	DC Blocking Voltage	600	V	
I <sub>F(AV)</sub>	Average Rectified Forward Current $@ T_C = 103^{\circ}C$	10	А	
I <sub>FSM</sub>	Non-repetitive Peak Surge Current 60Hz Single Half-Sine Wave	50	А	
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Temperature Range	-65 to +150	°C	

# **Thermal Characteristics**

123

Symbol	Parameter	Ratings	Units
$R_{ extsf{ heta}JC}$	Maximum Thermal Resistance, Junction to Case	7	°C/W

# Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
F20UP60DN	FFPF20UP60DNTU	TO-220F	-	-	50

Symbol	Parameter		Min.	Тур.	Max.	Units
V <sub>FM</sub> 1	I <sub>F</sub> = 10A I <sub>F</sub> = 10A	$T_{C} = 25^{\circ}C$ $T_{C} = 100^{\circ}C$		-	2.2 2.0	V
I <sub>RM</sub> 1	$V_{R} = 600V$ $V_{R} = 600V$	$T_{\rm C} = 25^{\rm o}{\rm C}$ $T_{\rm C} = 100^{\rm o}{\rm C}$	-	-	100 500	μA
t <sub>rr</sub>	I <sub>F</sub> = 10A, di/dt = 200A/µs, V <sub>R</sub> = 390V	$T_C = 25^{\circ}C$	-	53	70	ns
n n Q <sub>rr</sub>	I <sub>F</sub> = 1A, di/dt = 100A/µs, V <sub>R</sub> = 30V	$T_{\rm C} = 25^{\rm o}{\rm C}$	-	30 1.5 20	40 2 30	ns A nC
W <sub>AVL</sub>	Avalanche Energy (L = 40mH)		10	-	-	mJ

1: Pulse: Test Pulse width =  $300\mu$ s, Duty Cycle = 2%

.

 $\begin{array}{l} L=40mH\\ R<0.1\Omega\\ E_{AVL}=1/2LI^2 \end{array}$ 

 $Q_1 = IGBT (BV_{CES} > DUT V_{R(AVL)})$ 

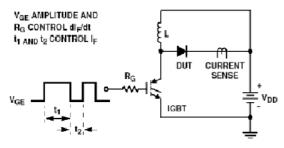
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Q1

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# **Test Circuit and Waveforms**



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trr TEST CIRCUIT

L R

+o V<sub>DD</sub>

V<sub>DD</sub>

- **9** 

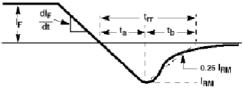
m

CURRENT

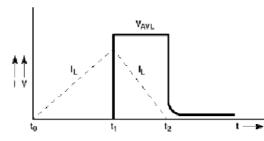
SENSE

DUT

AVALANCHE ENERGY TEST CIRCUIT



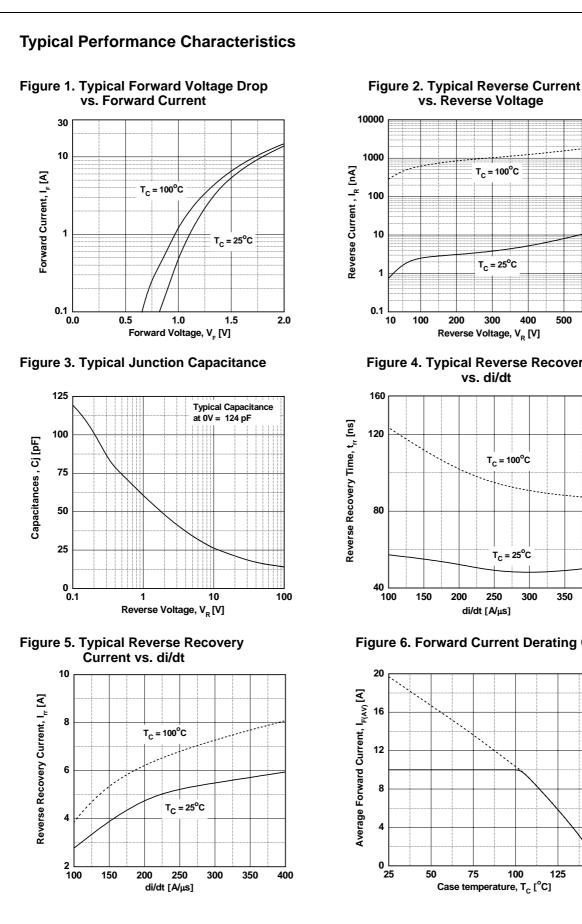
trr WAVEFORMS AND DEFINITIONS

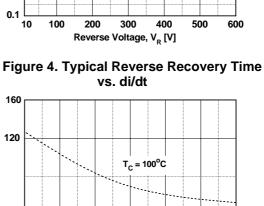


AVALANCHE CURRENT AND VOLTAGE WAVEFORMS

FFPF20UP60DN Rev.	А

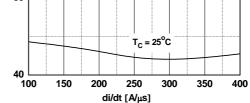
FFPF20UP60DN



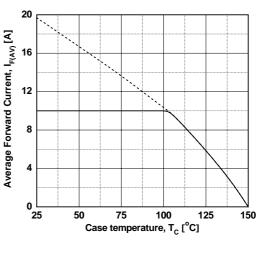


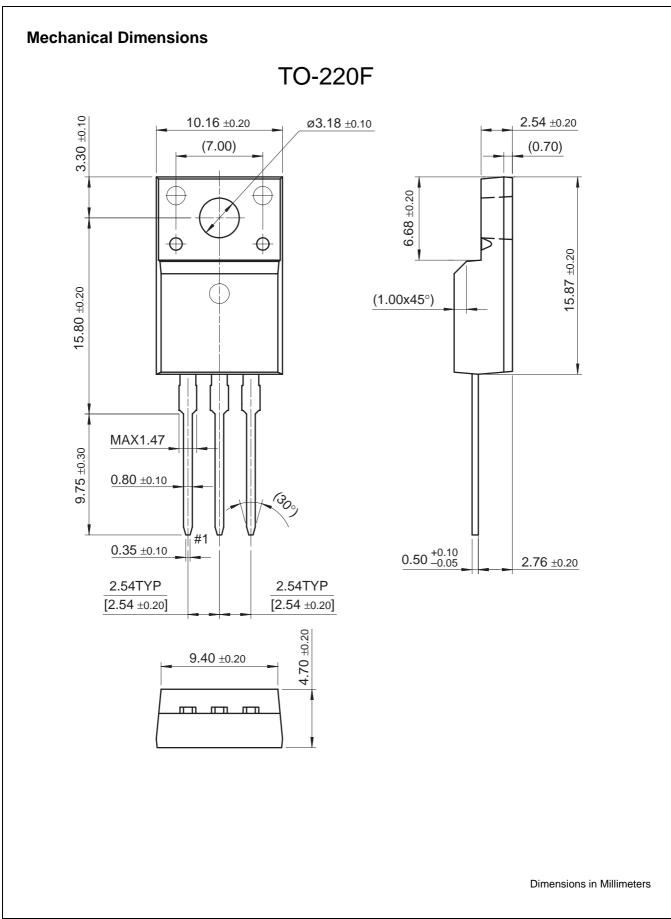
 $T_{C} = 100^{\circ}C$ 

 $T_{C} = 25^{\circ}C$ 









FFPF20UP60DN



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